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## **SOT-23 Formed SMD Package**

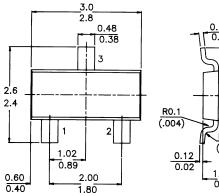
## **CMBT4123**

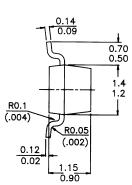
# GENERAL PURPOSE TRANSISTOR

N-P-N transistor

**Marking** CMBT4123 = 5B

PACKAGE OUTLINE DETAILS
ALL DIMENSIONS IN mm





#### Pin configuration

1 = BASE

2 = EMITTER

3 = COLLECTOR



# ABSOLUTE MAXIMUM RATINGS

Collector-base voltage (open emitter)	$-V_{CBO}$	max.	40	V
Collector-emitter voltage (open base)	$-V_{CEO}$	max.	30	V
Emitter-base voltage (open collector)	$-V_{EBO}$	max.	5	V
Collector current (d.c.)	$-I_C$	max.	200	mA
Total power dissipation at $T_{amb} = 25$ °C	$P_{tot}$	max	225	mW
D.C. current gain				
In 2 mA, Van 1 V	h	min.	<i>50</i>	
$-I_C = 2 \text{ mA}; -V_{CE} = 1 \text{ V}$	$h_{FE}$	max.	150	

## **RATINGS** (at $T_A = 25$ °C unless otherwise specified)

Limiting values

Collector-base voltage (open emitter)	$-V_{CBO}$	max.	40	V
Collector-emitter voltage (open base)	$-V_{CEO}$	max.	30	V
Emitter-base voltage (open collector)	$-V_{EBO}$	max.	5	V
Collector current (d.c.)	$-I_C$	max.	200	mA
Total power dissipation at $T_{amb} = 25^{\circ}C$	$P_{tot}$	max	225	mW

Storage temperature	$T_{stg}$		to +150	° C
Junction temperature	$T_j$	max.	150	° C
THERMAL CHARACTERISTICS				
$T_j = P (R_{th j-t} + R_{th s-a}) + T_{amb}$				
Thermal resistance				
from junction to ambient	$R_{th\ j-a}$		<i>556</i>	°C/mW
<b>CHARACTERISTICS</b> (at $T_A = 25^{\circ}C$ unless otherwis	e specified)			
Collector-emitter breakdown voltage	•			
$-I_C = 1 \text{ mA}; I_B = 0$	-V <sub>(BR)CEO</sub>	min.	30	V
Collector-base breakdown voltage	( )			
$-I_C = 10$ mA; $I_E = 0$	-V <sub>(BR)CBO</sub>	min.	40	V
Emitter-base breakdown voltage	, ,			
$-I_E = 10 \text{ mA}; I_C = 0$	−V <sub>(BR)EBO</sub>	min.	5	V
Collector cut-off current				
$-V_{CB} = 20 \ V; I_E = 0 \ V$	$-I_{CBO}$	max.	50	nA
Emitter cut-off current				
$V_{BE} = 3 V; I_C = 0$	$-I_{EBO}$	max.	50	nA
Output capacitance at $f = 100 \text{ kHz}$				
$I_E = 0$ ; $-V_{CB} = 5 V$	$C_c$	max.	4	pF
Input capacitance at $f = 100 \text{ kHz}$				
$I_C = 0; -V_{BE} = 0.5 V$	$C_e$	max.	8	pF
Saturation voltages				
$-I_C = 50 \text{ mA}; -I_B = 5 \text{ mA}$	$-V_{CEsat}$	max.	0.3	V
$-I_C = 50 \text{ mA}; -I_B = 5 \text{ mA}$	-V <sub>BEsat</sub>	max.	0.95	V
D.C. current gain				
$-I_C = 2 \text{ mA}; -V_{CE} = 1 \text{ V}$	$h_{\!F\!E}$	min.	50	
		max.	150	
$-I_C = 50 \text{ mA; } -V_{CE} = 1 \text{ V}$	$h_{FE}$	min.	25	
Noise figure at $R_S = 1 \text{ kW}$				
- $I_C = 100 \text{ mA}$ ; - $V_{CE} = 5 \text{ V}$				
f = 10  Hz to  15.7  kHz	NF	max.	6	dВ
1 - 10 112 to 13.7 KHZ	1 <b>V1</b>	шах.	U	uБ
Transition frequency				
$-I_C = 10 \text{ mA}; -V_{CE} = 20 \text{ V}; f = 100 \text{ MHz}$	$f_T$	min.	250	MHz
Small signal current gain				
$-V_{CE} = 1 \text{ V}; -I_{C} = 2 \text{ mA}; f = 1 \text{ KHz}$	$h_{fe}$	min.	50	
	1e	max.	200	
			200	

## **Customer Notes**

## **Disclaimer**

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